

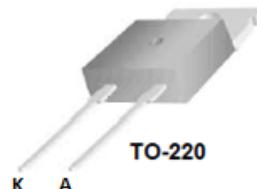
Ultrafast Soft Recovery Diode 30A 600V trr ~ 38 ns

Features

Ultrafast Recovery

175°C operating junction temperature

Designed and qualified for industrial level



Benefits

Reduced RFI and EMI

Higher frequency operation

Reduced snubbing

Reduced part count

Description/Applications

These diodes are optimized to reduce losses and EMI/RFI in high frequency power conditioning system. The softness of the recovery eliminates the need for a snubber in most applications.

These devices are ideally suited for HF welding power converters and other applications where switching losses are not significant portion of the total losses.

Absolute Maximum Ratings $T_c = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Values	Units
V_R	Cathode – Anode voltage	--	600	V
$I_{F(AV)}$	Continuous forward current	$T_c = 25^\circ\text{C}$	30	A
I_{FSM}	Single pulse forward current	$T_c = 25^\circ\text{C}$	300	A
I_{FRM}	Maximum repetitive forward current	Square wave 20 kHz	60	A
$T_{J,T_{STG}}$	Operating and Storage Temperature Range	--	-55 to +175	$^\circ\text{C}$

Thermal characteristics

Symbol	Parameter	Values	Units
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case	0.5	$^\circ\text{C}/\text{W}$
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	60	$^\circ\text{C}/\text{W}$

Electrical Characteristics $T_j = 25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Typ	Max	Units
V_{BR}, V_R	Breakdown Voltage, Blocking Voltage	$I_R = 100 \mu\text{A}$	600	--	--	V
V_F	Forward voltage	$I_F = 30 \text{ A}, T_J = 25^\circ\text{C}$	--	1.35	1.65	V
		$I_F = 30 \text{ A}, T_J = 125^\circ\text{C}$	--	1.2	1.5	V
I_R	Reverse Leakage Current	$V_R = V_R \text{ rated}$	--	--	1	μA
		$V_R = V_R \text{ rated}, T_J = 150^\circ\text{C}$	--	--	100	μA
trr	Reverse recovery time	$I_F = 0.5\text{A}, I_R = 1\text{A}, I_{RR} = 0.25\text{A}$	--	38	48	ns
		$I_F = 1\text{A}, V_R = 30\text{V}, \frac{dI}{dt} = -200\text{A/us}$	--	30		ns

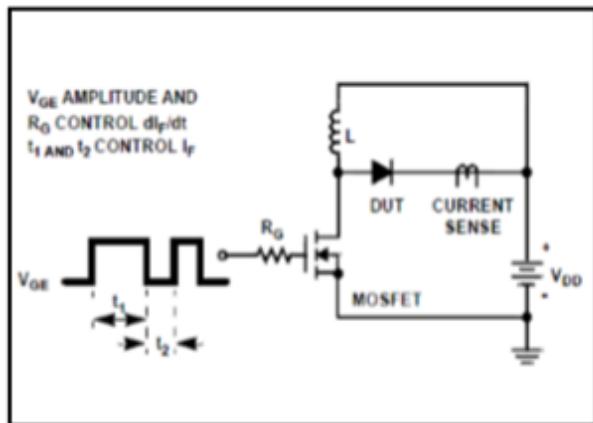


佳恩半导体
JIAENSEMI

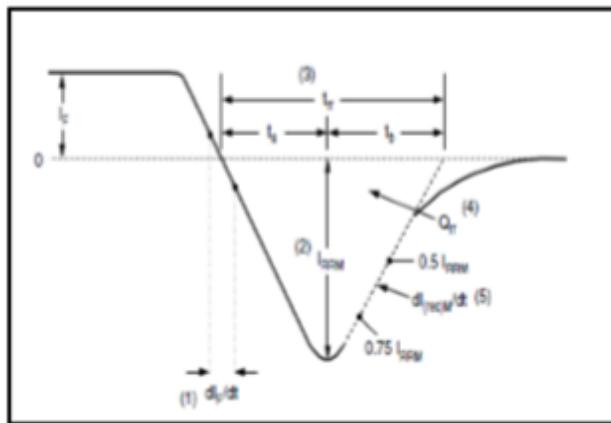
JDPC30U60AS

Trr Test Circuit

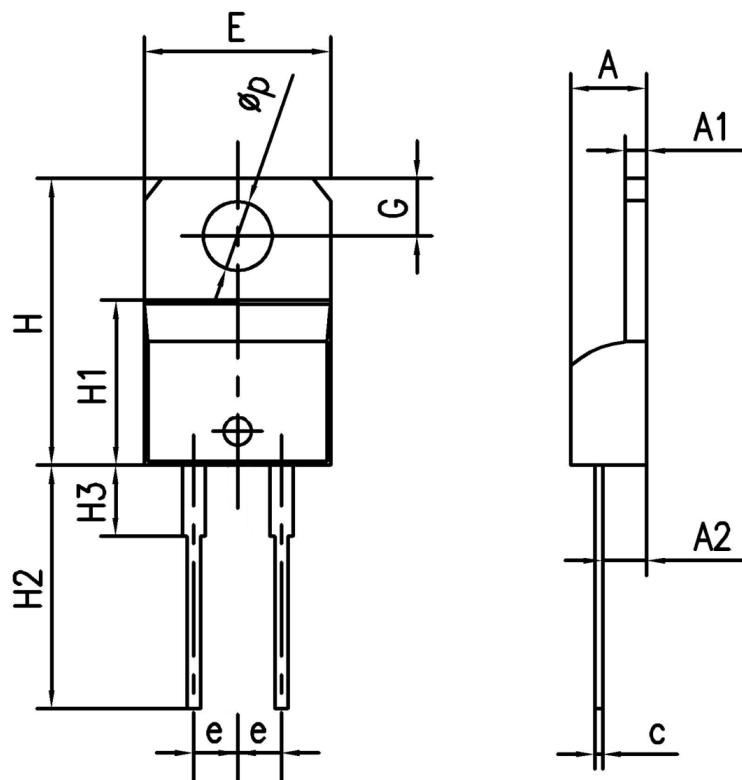
trr Test Circuit



trr Waveforms and Definitions



Package Information



	单位 mm		
	MIN	NOM	MAX
A	4.05	4.25	4.45
A1	1.15	1.25	1.35
A2	2.35	2.55	2.75
b	0.7	0.8	0.9
b1	1.22	1.32	1.42
c	0.4	0.45	0.5
e	2.34	2.54	2.74
E	9.95	10.15	10.35
H	15.3	15.5	15.7
H1	8.8	9	9.2
H2	13	13.5	14
H3	3.8	4	4.2
G	2.6	2.8	3
P	3.7	3.8	3.9

